

FRACTAL CONCEPTS IN SURFACE GROWTH

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Contents

<i>Preface</i>	xv
<i>Notation guide</i>	xix
PART 1 Introduction	1
1 Interfaces in nature	1
1.1 Interface motion in disordered media	3
1.2 Deposition processes	6
1.3 Biological systems	13
1.4 Methods of analysis	16
1.5 Discussion	18
2 Scaling concepts	19
2.1 Ballistic deposition	19
2.2 Roughening	20
2.3 Dynamic scaling	23
2.4 Correlations	25
2.5 Discussion	27
3 Fractal concepts	29
3.1 Self-similarity	29
3.2 Fractal dimension	30
3.3 Self-affinity	32
3.4 Discussion	36
PART 2 Nonequilibrium roughening	38
4 Random deposition	38
4.1 Definition	38

4.2	Exact solution	40
4.3	Stochastic growth equations	41
4.4	Discussion	42
5	Linear theory	44
5.1	Random deposition with surface relaxation	44
5.2	Symmetry principles	46
5.3	The Edwards–Wilkinson equation	48
5.4	Solving the EW equation	51
5.5	Discussion	54
6	Kardar–Parisi–Zhang equation	56
6.1	Construction of the KPZ equation	56
6.2	Excess velocity	58
6.3	Scaling arguments	60
6.4	Exponents	61
6.5	Discussion	63
7	Renormalization group approach	65
7.1	Basic concepts	65
7.2	Re-scaling in momentum space	69
7.3	Flow equations for the KPZ equation	71
7.4	Phase transition in the KPZ equation	73
7.5	Exponents for $d > 1$	74
7.6	Discussion	76
8	Discrete growth models	78
8.1	Ballistic deposition	78
8.2	Eden model	79
8.3	Solid-on-solid models	81
8.4	Propagation of interfaces in the Ising model	87
8.5	Numerical integration of the KPZ equation	88
8.6	Discussion	90
PART 3	Interfaces in random media	91
9	Basic phenomena	91
9.1	Depinning transition	92
9.2	Interfaces in a disordered medium	93
9.3	Scaling arguments	95
9.4	Thermal noise	97
9.5	Discussion	98

10	Quenched noise	99
10.1	Universality classes	100
10.2	Pinning by directed percolation	103
10.3	Isotropic growth models	109
10.4	Discussion	113
11	Experiments	115
11.1	Fluid flow in a porous medium	115
11.2	Paper wetting	119
11.3	Propagation of burning fronts	122
11.4	Growth of bacterial colonies	123
11.5	Rupture lines in paper sheets	125
11.6	Discussion	127
PART 4	Molecular beam epitaxy	128
12	Basic phenomena of MBE	128
12.1	Introduction	128
12.2	Microscopic processes on crystal surfaces	130
12.3	Discussion	136
13	Linear theory of MBE	139
13.1	Surface diffusion	139
13.2	Solving the diffusive growth equation	142
13.3	Growth with desorption	142
13.4	Discussion	144
14	Nonlinear theory for MBE	146
14.1	Surface diffusion: Nonlinear effects	146
14.2	Growth with desorption	150
14.3	Discussion	152
15	Discrete models for MBE	153
15.1	Irreversible growth models	154
15.2	Models with thermal activation	159
15.3	Hamiltonian models	163
15.4	Discussion	164
16	MBE experiments	166
16.1	Experimental techniques	167
16.2	Scaling approach for interface roughening	169
16.3	Dynamical properties	170

16.4	Discussion	172
17	Submonolayer deposition	175
17.1	Model	175
17.2	Scaling theory	176
17.3	Rate equations	180
17.4	Results from simulations	181
17.5	Extensions of the DDA model	183
17.6	Experimental results	187
17.7	Discussion	191
18	The roughening transition	192
18.1	Equilibrium fluctuations	192
18.2	Discrete models and experimental tests	199
18.3	Nonequilibrium effects	201
18.4	Discussion	206
19	Nonlocal growth models	209
19.1	Diffusion-limited aggregation	209
19.2	Sputter deposition	212
19.3	Experimental results on sputter deposition	219
19.4	Roughening by ion bombardment	225
19.5	Discussion	229
20	Diffusion bias	231
20.1	Diffusion bias and instabilities	231
20.2	Nonlinear theory	232
20.3	Discrete models	235
20.4	Experimental support	237
20.5	Discussion	239
PART 5	Noise	240
21	Diffusive versus deposition noise	240
21.1	Conservative noise	240
21.2	Linear theory	241
21.3	Scaling regimes	242
21.4	Nonlinear theory	243
21.5	Discussion	244
22	Correlated noise	245
22.1	Introducing correlated noise	246

22.2	Linear theory with correlated noise	246
22.3	KPZ equation with spatially-correlated noise	248
22.4	KPZ equation with temporally-correlated noise	250
22.5	Discussion	252
23	Rare events	253
23.1	Linear theory	254
23.2	Nonlinear theory	257
23.3	Multi-affinity	259
23.4	Discussion	261
PART 6	Advanced topics	262
24	Multi-affine surfaces	262
24.1	Hierarchy of scaling exponents	263
24.2	A deterministic multi-affine model	264
24.3	Brownian motion	266
24.4	Local dimensions	266
25	Variants of the KPZ equation	269
25.1	Deterministic KPZ equation	269
25.2	Anisotropic KPZ equation	271
25.3	Universal amplitudes	275
25.4	Discussion	276
26	Equilibrium fluctuations and directed polymers	277
26.1	Discrete model	277
26.2	Scaling properties	278
26.3	Continuum description	279
26.4	Equilibrium theory	280
26.5	Discussion	284
PART 7	Finale	285
27	Summary of the continuum growth equations	285
27.1	Universality classes	285
27.2	Nomenclature	287
27.3	Related problems	289
27.4	Discussion	296
28	Outlook	298

APPENDIX A Numerical recipes	301
A.1 Measuring exponents for self-affine interfaces	301
A.2 The coefficient λ of the nonlinear term	307
A.3 Intrinsic width	309
A.4 Measuring surface diffusion currents	310
A.5 Generating noise in simulations	311
 APPENDIX B Dynamic renormalization group	 315
B.1 Introduction	315
B.2 Perturbation expansion	316
B.3 Renormalization procedure	323
B.4 Calculation of the integrals	325
 APPENDIX C Hamiltonian description	 330
 <i>Bibliography</i>	 332
<i>Index</i>	359

I Interfaces in nature

Most of our life takes place on the surface of something. Sitting on a rock means contact with its surface. We all walk on the surface of the Earth and most of us don't care that the center of the Earth is molten. Even when we care about the interior, we cannot reach it without first crossing a surface. For a biological cell, the surface membrane acts not only as a highly selective barrier, but many important processes take place directly on the surface itself.

We become accustomed to the shapes of the interfaces we encounter, so it can be surprising that their morphologies can appear to be quite different depending on the scale with which we observe them. For example, an astronaut in space sees Earth as a smooth ball. However Earth appears to be anything but smooth when climbing a mountain, as we encounter a seemingly endless hierarchy of ups and downs along our way.

We can already draw one conclusion: surfaces can be smooth, such as the Himalayas viewed from space, but the same surface can also be rough, such as the same mountains viewed from earth. In general the *morphology depends on the length scale of observation*!

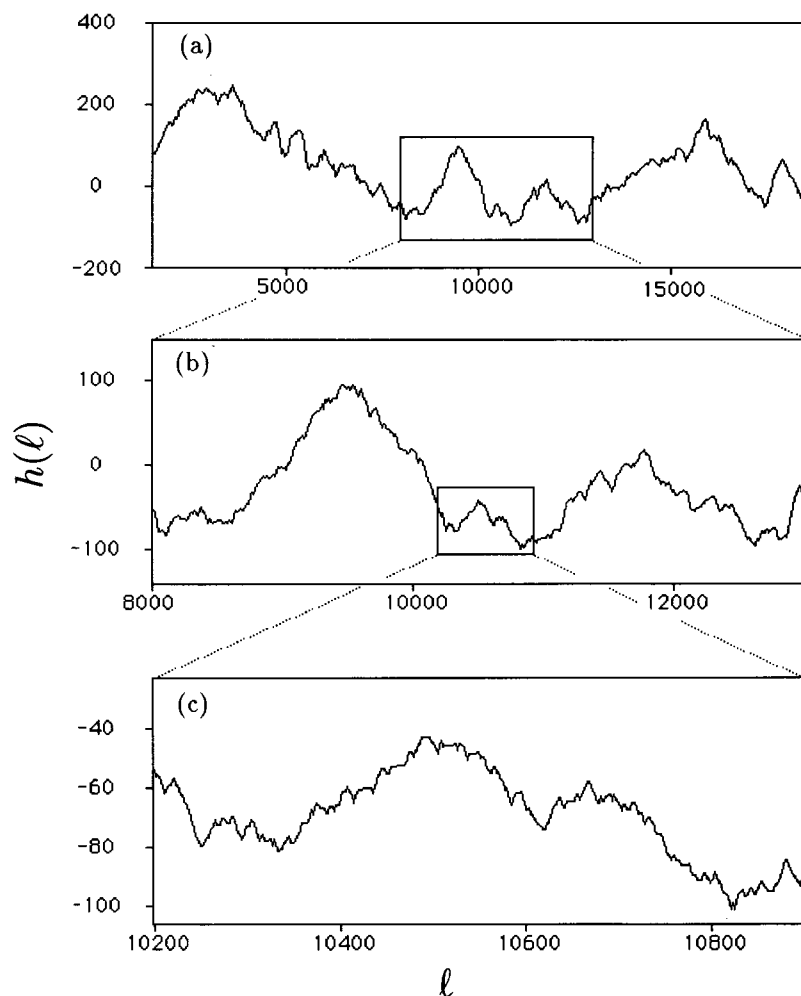
How can we describe the morphology of something that is smooth to the eye, but rough under a microscope? This is one question we shall try to answer in this book. To this end, we will develop methods to characterize quantitatively the morphology of an arbitrary interface. In fact, we shall see that concepts like roughness are replaced by exponents that refer not to the roughness itself, but to the fashion in which the roughness *changes* when the observation scale itself changes.

Fractal objects in nature are the same on different observation scales. However, the above examples look rather different when the scale is changed. Does this fact imply that the title of this book is a misnomer? Yes and no. In fact, many interfaces and surfaces are

examples of *self-affine* objects, which are ‘intermediate’ between fractal objects and non-fractal objects in the following sense. When we make a scale change that is the *same in all directions*, self-affine objects change morphology. On the other hand, when we make a scale change that is *different for each direction*, then interfaces do not change morphology. Rather, they behave like fractal objects in that they appear the same before and after the transformation (see Fig. 1.1).

This book will explore in some detail the nature of such self-affine objects. We shall see that this feature is analogous to a ‘symmetry principle.’ Symmetry principles codified in group theory enable one

Figure 1.1 Rescaling a self-affine function, in this case the ‘DNA walk’ introduced in §1.3.2 (cf. Fig. 1.13). Only if the two unequal magnification factors, M_ℓ and M_h , by which the ℓ and h directions are re-scaled, are selected correctly will the enlarged portion have the same statistical properties as the original. (After [416].)



to classify and eventually understand some properties of a crystalline system. Similarly, the symmetry obeyed by self-affine objects will enable us to classify and perhaps better understand some properties of rough interfaces in nature.

We are interested not only in the *morphology* of various ‘pre-formed’ interfaces, but also in the dynamics of how the morphology develops in time. Some surfaces are formed as a result of a deposition process. Others shrink due to erosion or etching. Some interfaces propagate through inhomogeneous media. An interesting set of questions concerns the *formation, growth, and dynamics* of such interfaces.

In this first chapter, we offer the interested reader an *apéritif* – by exposing a variety of the themes of this book without the baggage imposed by requiring equations or discussing experimental details. The reader whose appetite is already ‘up’ for the main course is invited to proceed directly to Chapter 2.

1.1 Interface motion in disordered media

1.1.1 Fluid flow in porous media

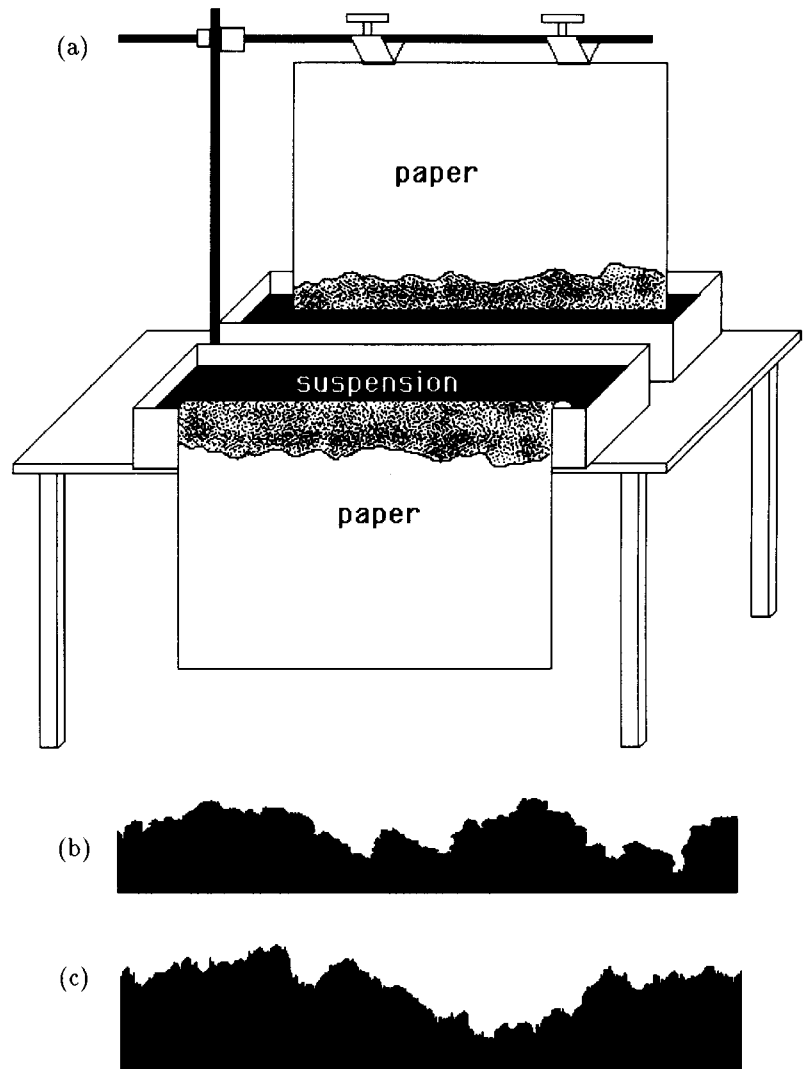
A familiar scene: at breakfast, your spilled coffee suddenly conquers a segment of the tablecloth. Probably this is not the right moment to contemplate the microscopic forces that balance just when the coffee stops spreading. Nor is it the appropriate moment to start thinking about the shape of the patch, or the roughness of its surface. So wait until the stress subsides, and then examine the large brown patch.

By clipping a paper towel on a stand and immersing one end into a fluid, we can repeat the coffee accident on a laboratory benchtop. Paper is an inhomogeneous material, a prototype of the porous inhomogeneous rock that holds oil! One difference between fluid flow in the paper towel and in oil-bearing rock arises from the length scales at which these phenomena take place. This difference is an advantage: we can use a 20 cm paper towel system (Fig. 1.2) to help develop our understanding of the 20 km oilfield problem. For example, we can characterize the wet–dry interface using scaling laws, whose form is predicted by simple models that capture the essential mechanisms contributing to the morphology. This ‘benchtop exercise’ is an example of some of the current experiments being carried out on idealized systems which are yielding new insights into practical interface problems.

1.1.2 Propagation of flame fronts

Take a sheet of paper and ignite it at one end. Try to keep it horizontal, so that the entire paper does not take flame at once – if possible, use paper that burns without flame. After burning a part of it, inspect the interface between the burned and unburned parts (see Fig. 1.3). Is it rough, similar to the edge of the coffee droplet on the tablecloth? Is this similarity a coincidence, or there is something in common between these processes?

Figure 1.2
 (a) Schematic illustration of an experimental setup probing interface motion in random media. Parameters such as type of paper, temperature, humidity, direction of growth and concentration of coffee can be varied systematically. These changes affect the area, the speed of wetting, and the global width of the rough surface, but they do not affect the scaling properties of the surface.
 (b) Digitized experimental interface; the horizontal size of the paper was 20 cm.
 (c) Typical result of a discrete model mimicking interface motion in disordered media (see §10.2).
 (After [31]).



1.1.3 Flux lines in a superconductor

Suppose we place a superconductor in an external magnetic field. The field penetrates the material by generating flux lines or vortices, each carrying an elementary flux (see Fig. 1.4). If there are no impurities in the superconductor and the temperature is low, the flux lines form an array of straight lines. If there are impurities in the superconductor, the flux lines stretch to get close to the impurity sites. These individual flux lines are rough, resembling the surface of the coffee drop, or the fire front. However, there is one important difference between a flux line and a fire or fluid interface: a firefront is a topologically one-dimensional object moving in a two-dimensional plane, while a

Figure 1.3 An 8 cm segment of paper in which fire propagates from below. (After [504]).

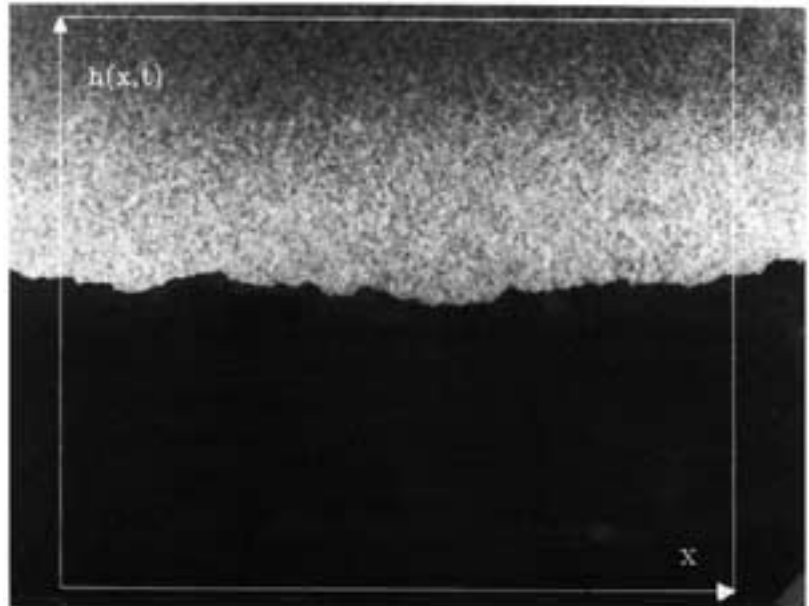
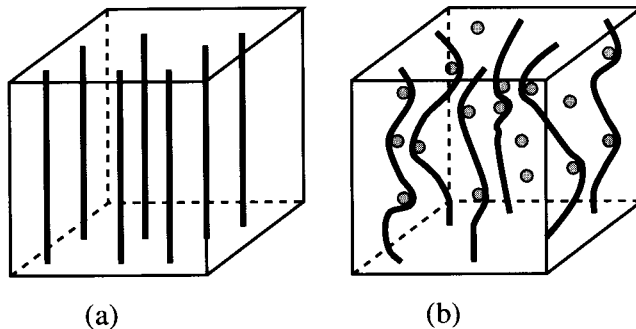


Figure 1.4 Vortex lines in a type II superconductor.

(a) In a perfectly clean superconductor at low temperatures the flux lines form an ordered lattice.

(b) When the temperature is increased, thermal fluctuations destroy the ordered lattice and the flux lines become wavy. If there are impurities (shaded circles) in the superconductor, the flux lines are pinned in random positions of the impurities.



flux line is a topologically one-dimensional object fluctuating in a *three-dimensional* space.

One purpose of this book is to discuss apparently different phenomena using a common framework. It is coming to be appreciated that all the systems discussed in this section display essentially the same physics: there is an elastic interface ('elastic' in the sense that it does not break, but tries to remain smooth) which propagates in a disordered material. The randomness of the substrate acts to pin the interface, thereby making the interface rough. In the fluid case, local inhomogeneities may block the fluid flow. Some parts of the paper do not burn as rapidly as others, so the flame is halted. Impurities attract the flux line and pin it down in random positions. We shall see that these systems are described by the same laws, and that they can be studied using a similar set of numerical and analytical methods.

1.2 Deposition processes

Winter. Look out of your car window – snow is falling. The larger snowflakes slide down the window slowly, and form the aggregate shown in Fig. 1.5(a). Notice that at length scales comparable to the size of the snowflake the aggregate is very rough. Why? Snowflakes are deposited randomly. Once they arrive at the aggregate, they stick. The *randomness* in the deposition process apparently leads to a *rough* surface. A similar deposition process is illustrated in Fig. 1.5(b). The resulting bulk is nearly homogeneous, but the surface is quite rough. These are but two of the many examples for which random deposition of some material occurs, and we witness the dynamic growth of a rough surface.

1.2.1 Atom deposition

A deposition process of greater technological importance than snowfall takes place during the growth of thin films by molecular beam epitaxy (MBE), a technology used to manufacture computer chips and other semiconductor devices, indispensable in today's technological world. The most common element used in computer chips is silicon. An example of a very clean Si surface is shown in Fig. 1.6, obtained using a scanning tunneling microscope (STM).

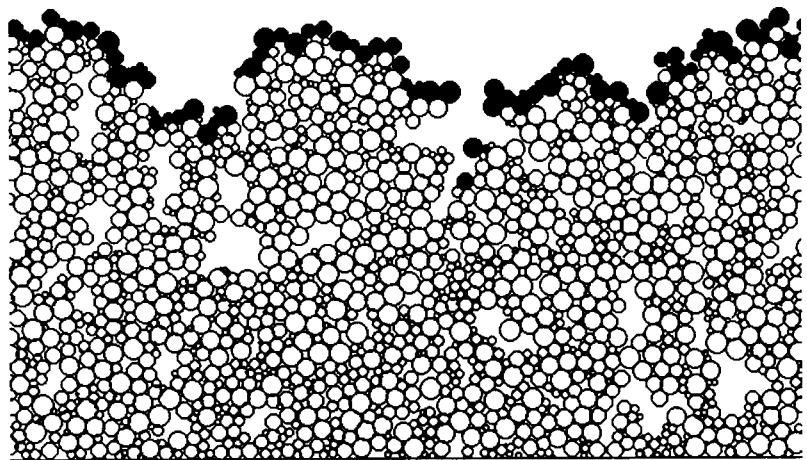
Now imagine that you start depositing new atoms on this Si surface. In contrast to the snowflakes that stick on the first contact point, the Si atom does not stick, but diffuses. When a Si atom reaches the edge

of a step, it forms covalent bonds with neighboring atoms, and sticks with a high probability. Such bonds may be broken again, but with a low probability. If the incoming flux is large, there is a large number

Figure 1.5 (a) Snow particles falling on a slanted glass window (After [270]); (b) The interface generated by a simple deposition model, in which spherical particles with uniformly distributed random diameters arrive on the surface and roll until they make contact with at least two other discs. (After [89]).



(a)



(b)

Figure 1.6 A Si surface, as examined by STM. One can distinguish both individual atoms and vacancies. The rugged lines correspond to steps on the surface, where the height of the interface increases by one atom. (Courtesy of M. Lagally).

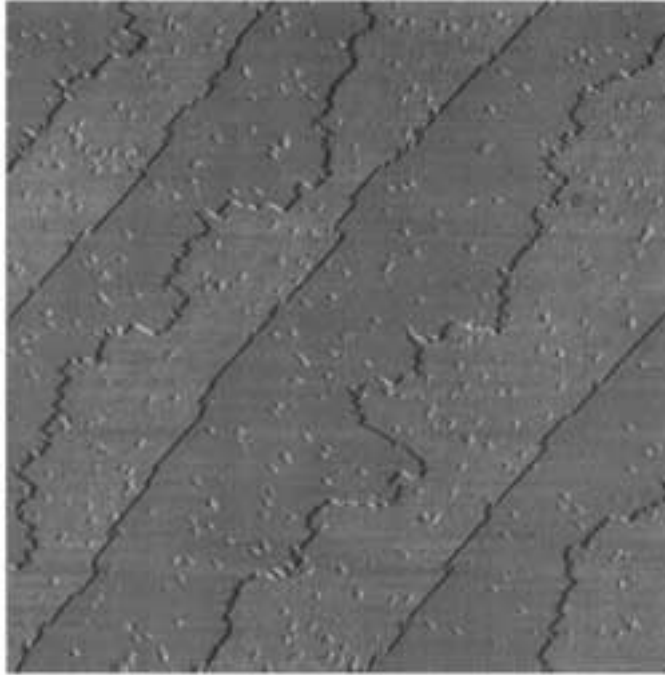


Figure 1.7 Formation of islands by atoms deposition on a Si surface. (Courtesy of M. Lagally).

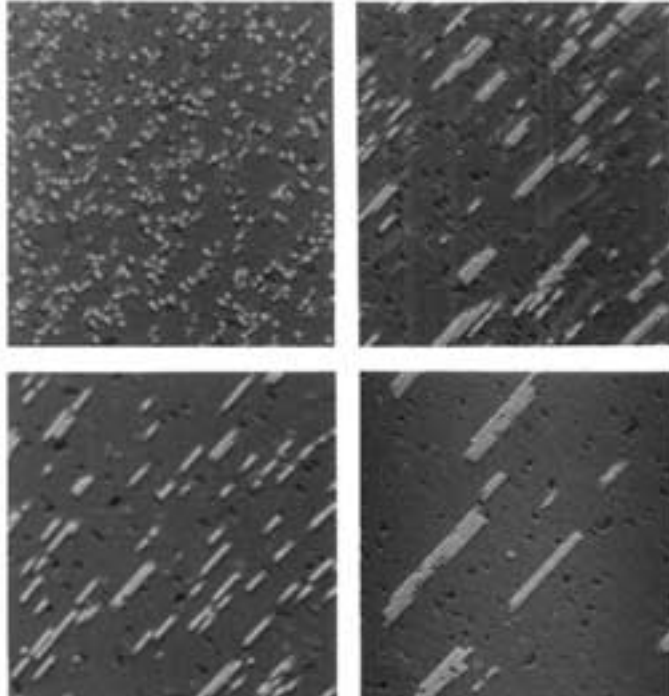
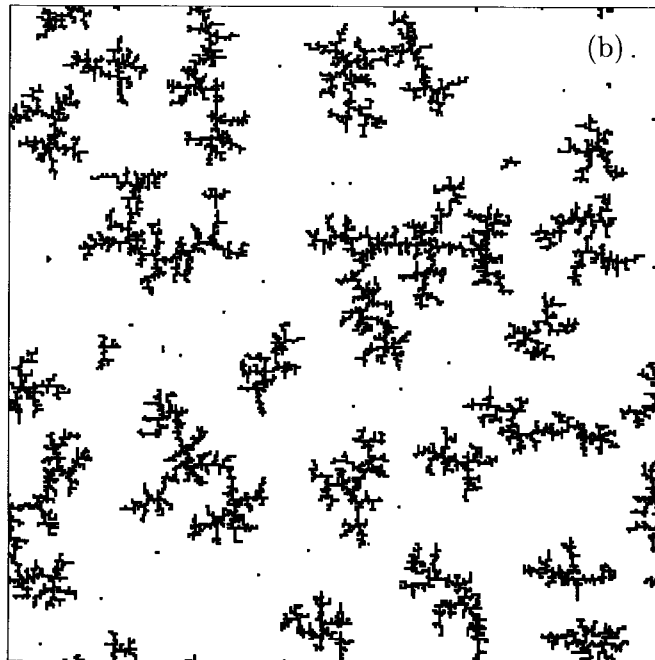
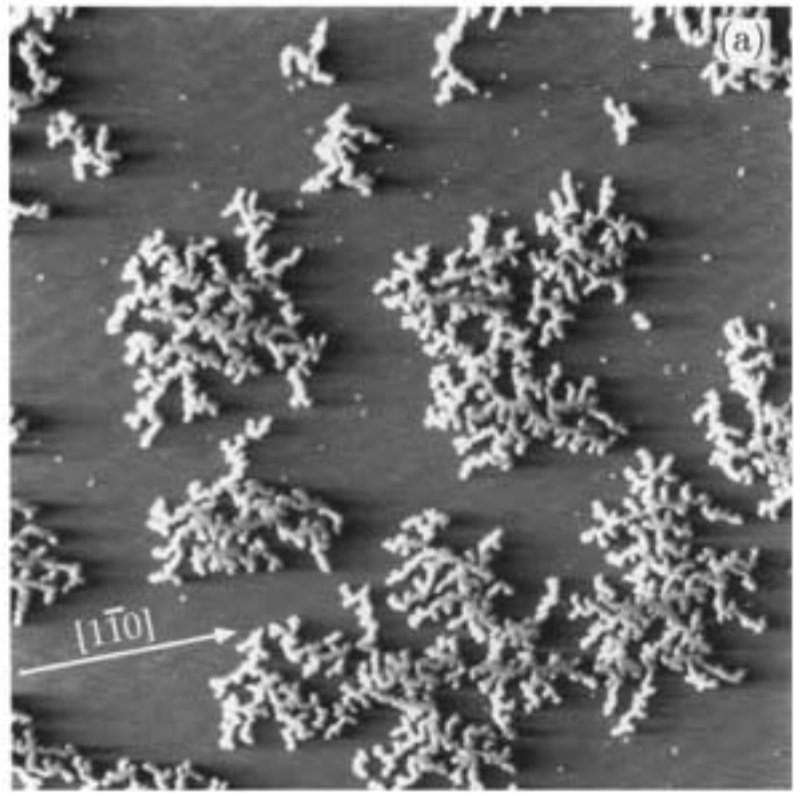


Figure 1.8
(a) Branched island morphologies obtained by Ag atom deposition on Pt at 110 K. (After [57]).
(b) Island formation in a model incorporating the three basic processes taking place during MBE: deposition, diffusion, and aggregation. The deposited atoms aggregate due to diffusion, generating branched fractal islands, similar to those observed in (a). (After [197]).



of wandering atoms on the surface, which meet and ‘glue’ together, forming islands (see Fig. 1.7).

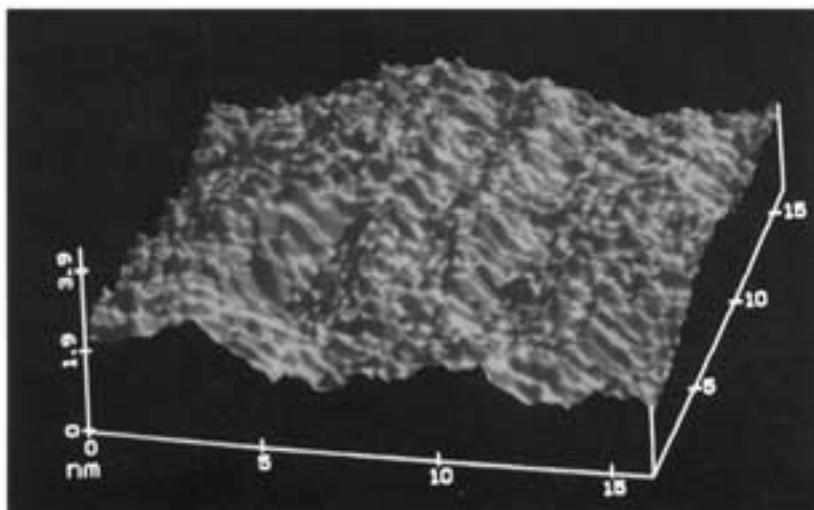
The islands do not always have a regular shape. As Fig. 1.8 illustrates, Ag deposition on Pt surfaces leads to branched structures, which are known to be self-similar, or fractal. What is the difference between the Si and the Pt that accounts for the difference in island structure? Is it related to the difference in the material properties, or only to the different temperatures and deposition rates?

1.2.2 Roughening in MBE

If we continue to deposit atoms, smaller islands will form on the top of the larger islands. The interface eventually becomes quite rough (see Fig. 1.9). Our discussion so far suggests that we may be happy whenever we see a rough surface. However, engineers usually wish to make a *smooth* film, since rough surfaces have poor contact properties and cannot be used in most applications. In order to avoid roughness, one first must understand the basic mechanism leading to roughness, and the processes affecting the morphology in general. This understanding then may be explored to grow films in regimes where roughening is reduced or absent.

Another common method used in film deposition experiments is sputtering. During *sputter erosion* the material is bombarded with an ion beam that hits the surface and kicks out atoms. This process is used to clean a surface, by eroding a few layers – or, by guiding

Figure 1.9 STM image of a rough Ag substrate. (After [243]).



the eroded atoms towards a sample, to grow another surface by a process called *sputter deposition*. Films grown by sputter deposition sometimes develop interesting ‘cauliflower’ structures, as is shown in Fig. 1.10. Why do these manmade films resemble so well the natural cauliflower?

The actual surface morphology in sputter erosion depends on the experimental conditions; some experiments lead to rough interfaces, others to periodic ripple structures (Fig. 1.11). What is the mechanism of the roughening process? Is erosion simply the inverse of deposition, or does it involve processes not present during deposition? How do we explain the formation of the ripple structures on the surface?

Figure 1.10
Micrographs showing
the similarity in
morphology for
various materials at
different
magnifications –
these span roughly
six orders of
magnitude in linear
dimension. (a) TEM
micrograph of *a*-Ge;
(b) SEM micrograph
of *a*-Si on glass
substrate; (c) SEM
micrograph of *a*-Si
on polycrystalline Al
substrate; (d) optical
micrograph of
pyrolytic graphite;
(e) optical
micrograph of a
thick metal film, and
(f) photograph of a
cauliflower. (After
[316]).

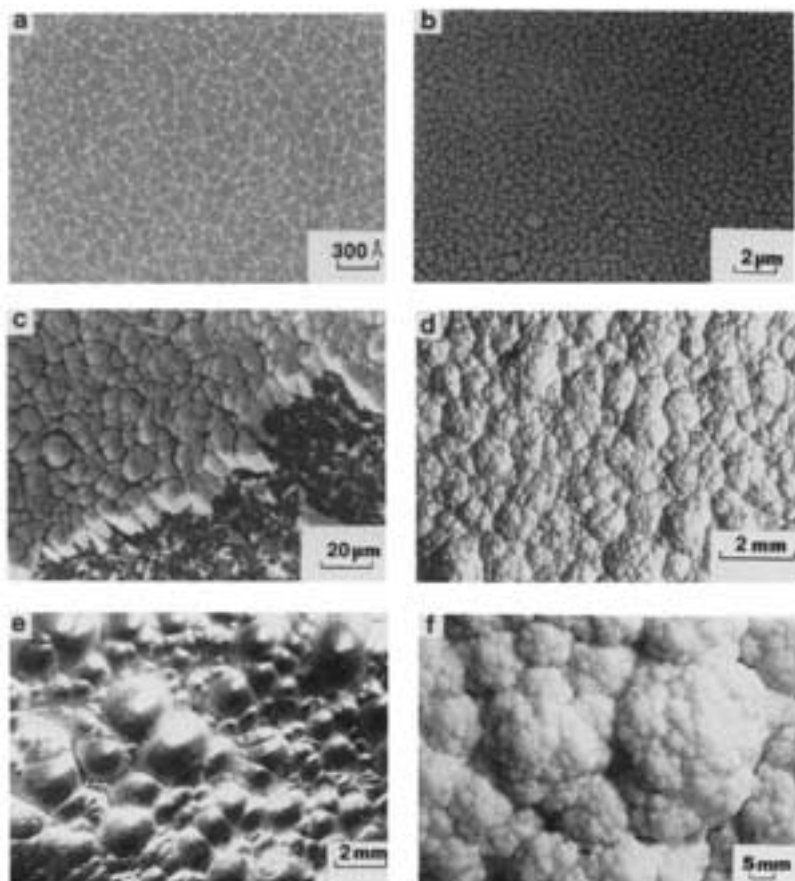
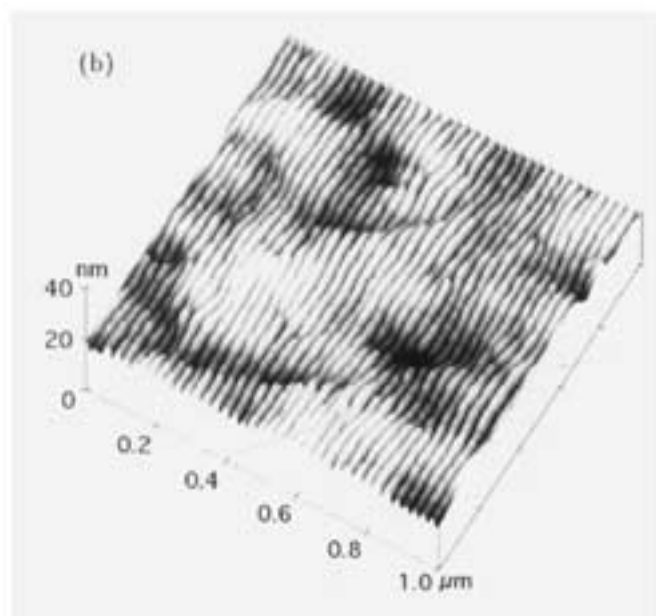
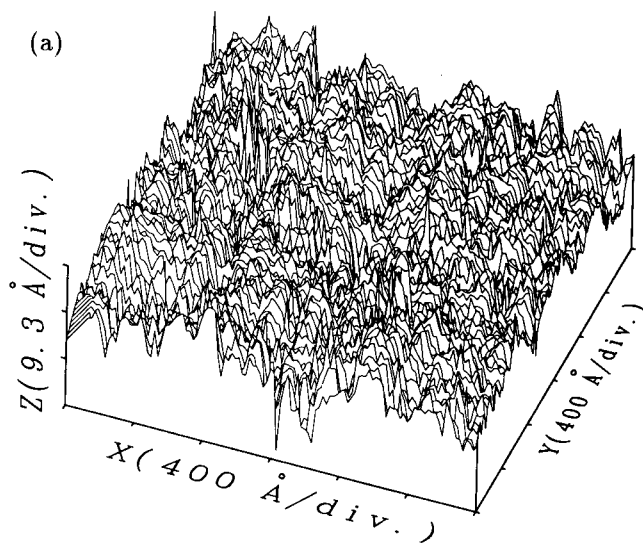


Figure 1.11 (a) STM topograph of a graphite surface after bombarding with a flux $F = 6.9 \times 10^{13}$ ions. $\text{cm}^{-2}\text{sec}^{-1}$ and an ion fluence $Q = 10^{16}$ ions/ cm^2 at room temperature.

The sample size is $2400 \text{ \AA} \times 2400 \text{ \AA}$, and the vertical size 18.6 \AA . (After [114]).

(b) Atomic force microscope image of a Xe-bombarded SiO_2 film. Note the periodic ripple structure. (After [301]).



1.3 Biological systems

1.3.1 Bacterial growth

The previous examples were selected from the field of materials science. But there are also interesting interfaces in biology. Let us consider a much-studied problem, the growth of bacterial colonies. In a typical experimental setup, agar is prepared in a petri dish. In the middle of the agar a bacterium is inoculated, whereupon it multiplies. At microscopic length scales, the bacteria exhibit a random motion. Looking from a distance, however, a range of interesting morphologies can be observed (Fig. 1.12). The actual morphology depends on the nutrient concentration and on other experimentally-controllable parameters. Some colonies have a compact shape, with a rough surface, similar to the morphology we confronted with spilt coffee. Others are branched, reminiscent of the islands observed in atomic deposition. Are there some general principles common to bacterial growth, island formation, and fluid flow?

1.3.2 DNA

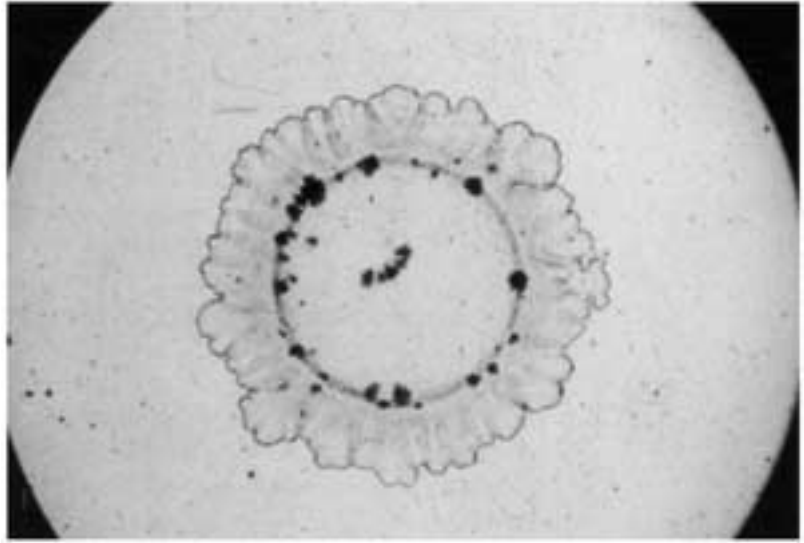
Many systems develop well-defined interfaces. However, there are processes that do not have a surface at all, but with a natural choice of variables can be mapped to a mathematical function or 'landscape' whose roughness is amenable to analysis using the same methods used for real interfaces.

An example that at first sight has nothing to do with interfaces is one-dimensional Brownian motion. Consider a drunk in an elevator of a skyscraper. Let us imagine that the elevator has only two buttons, up and down: the up button takes the elevator one level up, the down button one level down. The drunk punches the buttons randomly. If we plot the position of the elevator as a function of time, we obtain a jagged landscape, called the trail of the random walk, which may be described by many of the same methods used to quantify interface morphology.

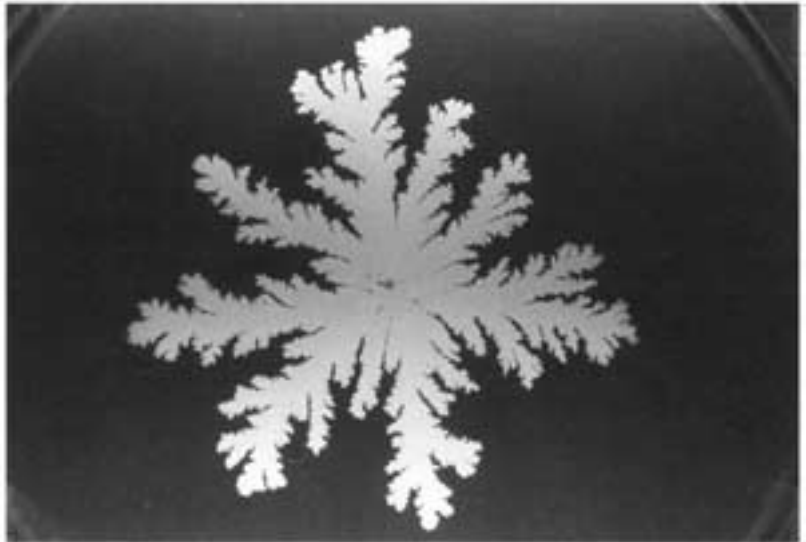
Genomic DNA sequences code for protein structure. The human genome contains information for approximately 100 000 different proteins, which define all inheritable features of an individual – it is likely the most sophisticated information database, created entirely through the dynamic process of evolution.

The building blocks for coding this information, called *base pairs*, form two classes, purines and pyrimidines. In order to study the correlations of a DNA sequence, one can introduce a graphical rep-

Figure 1.12
Examples of bacteria
colonies. (a) A
colony with roughly
compact shape.
(After [39].) (b) A
colony with a
branched
morphology,
resembling the DLA
growth model
described in Chapter
19. (After [296]).



(a)

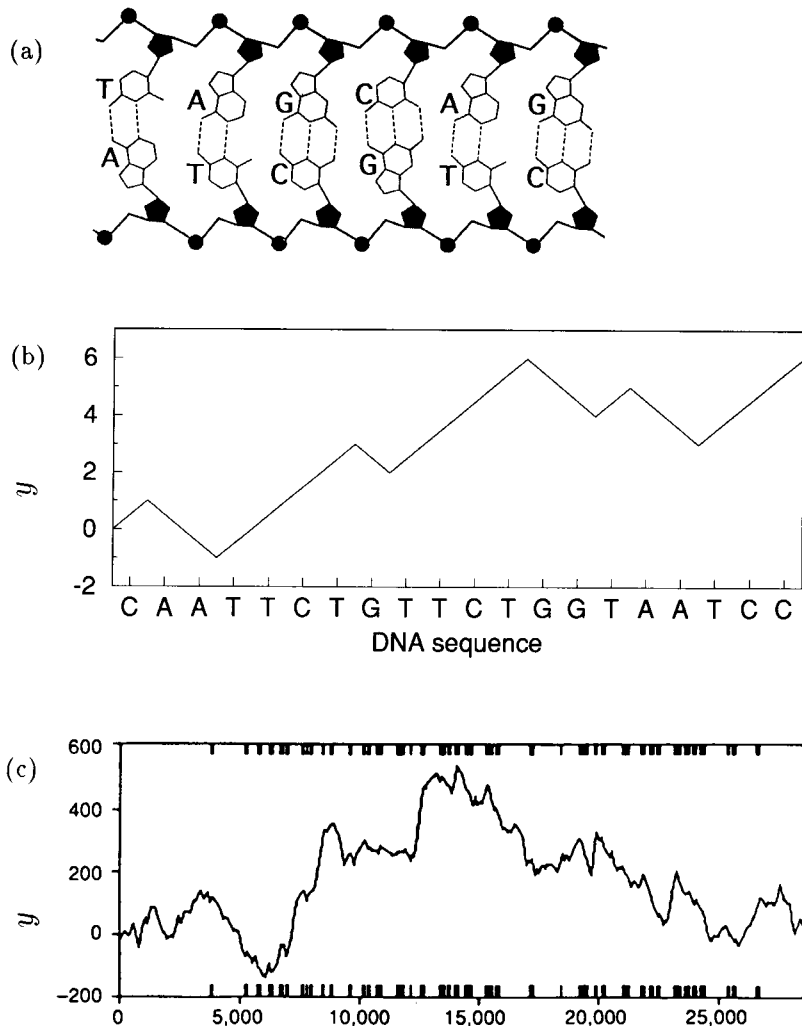


(b)

representation of the base pair sequence. This 'DNA walk' allows one to visualize directly the fluctuations of the purine-pyrimidine content in DNA sequences: an 'uphill drift' in a region of the landscape corresponds to high local concentration of pyrimidines, while a 'downhill drift' corresponds to high local concentration of purines.

Figure 1.13 shows a typical example of a gene that contains a significant fraction of base pairs that do *not* code for amino acids. The advantage of the DNA walk representation is that it can be quantitatively studied using the methods developed for interfaces. The methods reveal the surprising fact that such noncoding DNA,

Figure 1.13 (a) The base pairing of two DNA strands to form a double helix. So far as the information content is concerned, a DNA sequence can be represented as a symbolic sequence of four letters: A, C, G and T. (b) Schematic illustration of the definition of the 'DNA walk'. The walker steps 'up' [$u(i) = +1$] if a pyrimidine (C or T) occurs at position i along the DNA chain, while the walker steps 'down' [$u(i) = -1$] if a purine (A or G) occurs at position i . (c) DNA walk for a DNA sequence comprising more than 25 000 base pairs. (After [60]).



previously believed to have at most correlations of very short range, in fact displays long-range correlations [60]. The implications of this result for the possible language characterizing the noncoding DNA is a topic under current investigation [290].

1.4 Methods of analysis

Each field has its own methods for treating a given problem. The development of new approaches, with more descriptive and predicting power, is one of the major goals of science. For the field of disorderly surface growth there are a number of standard tools that must be mastered. We briefly discuss four important methods that are developed and used throughout the book.

1.4.1 Scaling concepts

One of the modern concepts used to study various roughening processes is *scaling*. Scaling has a surprising power of prediction, simple manipulations allowing us to connect apparently independent quantities and exponents.

We shall see that many measurable quantities obey simple *scaling relations*. For example, for a large number of systems we shall find that the interface width, $w(t)$, increases as a power of time, $w(t) \sim t^\beta$. The width eventually saturates at a value that increases as a power law of the system size, $w(L) \sim L^\alpha$.

Studying such scaling relations will allow us to define *universality classes*. The universality class concept is a product of modern statistical mechanics, and codifies the fact that there are but a few essential factors that determine the exponents characterizing the scaling behavior. Thus different systems which at first sight may appear to have no connection between them, behave in a remarkably similar fashion.

The values of the exponents α and β are independent of many ‘details’ of the system. For example, α and β do not depend on whether we immerse the paper in ink or coffee, or if we use a paper towel or a tablecloth. In fact, we shall see that the scaling exponents obtained for the fluid flow problem coincide with the scaling exponents obtained for the burning front, despite the rather different mechanisms leading to the actual interface.